3-Phase Diode Bridge 60

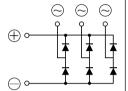
«Features»

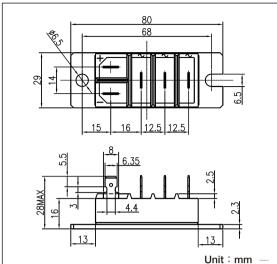
Power Diode Module DF30CA is designed for three phase full wave rectification, which has six diodes connected in a three phase bridge configuration. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction output DC current is 30Amp (Tc=122°C) Repetitive peak reverse voltage is up to 1,600V.

- IFSM=775/850A(50/60Hz) TjMax=150℃
- Isolated Mounting Base
- High reliability by unique glass passivation
- Easy Assemble by the #250 terminal Tab

«Applications**»**

·AC. DC Motor Drive / AVR / Switching — for three phase rectification





■ Maximum Ratings (Tj=25°C unless otherwise specified)

| Item | Symbol | Unit | DF30CA80 | DF30CA160 |
|-------------------------------------|------------------|------|----------|-----------|
| Repetitive Peak Reverse Voltage | V _{RRM} | V | 800 | 1600 |
| Non-Repetitive Peak Reverse Voltage | V _{RSM} | V | 960 | 1700 |

| Ite | em | Symbol | Unit | Ratings | Conditions |
|---------------------|-------------------|------------------|----------|-------------|--------------------------------------------|
| Output Current(D.C |).) | I _D | А | 30 | T _c =122°C |
| Surge Forward Curr | rent | I _{FSM} | А | 775/850 | 1/2cycle,50/60Hz,Peak value,non-repetitive |
| Operating Junction | Temperture | Tj | °C | -40 to +150 | |
| Storage Temperatu | re | T _{stg} | °C | -40 to +125 | |
| Isolation Breakdowr | n Voltage(R.M.S.) | | V | 2500 | A.C.1minute |
| Mounting torque | Mounting M6 | | N·m | 4.7(48) | Recommended Value 2.5 to 3.9 (25 to 40) |
| | Mounting M5 | | (kgf∙cm) | 2.7(28) | Recommended Value 1.5 to 2.5 (15 to 25) |
| Mass | | | g | 90 | Typical |

Electrical Characteristics (Tj=25°C unless otherwise specified)

| Item | Symbol | Unit | Ratings | | | Conditions |
|---------------------------------|----------------------|------|---------|------|------|--------------------------------------------------------------------------------------------|
| | | | Min. | Тур. | Max. | Conditions |
| Repetitive Peak Reverse Current | I _{RRM} | mA | | | 12 | T _j =150°C at V _{RRM} |
| Forward Voltage Drop | V _{FM} | V | | | 1.1 | Forward current 30A |
| Threshold Voltage | V _(TO) | V | | | 0.85 | T _j =150°C |
| Dynamic Resistance | rt | mΩ | | | 3.8 | T _j =150°C |
| Thermal Resistance | R _{th(j−c)} | °C/W | | | 0.42 | Junction to case per module |
| Interface Thermal Resistance | $R_{th(c-f)}$ | °C/W | | | 0.1 | Case to Heat Sink Thermal conductivity(Silicon grease) ≒7×10 ⁻³ [W/cm·°C] |



UL; E76102

DF30CA80/160

